General Description

The MAX4598 low-voltage, CMOS analog IC is a configurable single-ended 8-to-1/differential 4-to-1 multiplexer. In addition to the input channels, both V+ and GND can be switched to the output channels, enabling the supply voltages to be monitored. The MAX4598 operates from a single +2.7V to +12V supply or from dual ±6V supplies. The device has low on-resistance (75 Ω max) and TTL-compatible logic inputs from either ±5V or a single +5V supply. Each switch can handle Rail-to-Rail[®] analog signals. The MAX4598 has two modes of operation: as a standard multiplexer and as a "latchable" multiplexer where the address lines are strobed. The off-leakage current is only 0.1nA at T_A = +25°C and 2nA at T_A = +85°C. ESD protection is > 2kV per Method 3015.7.

The MAX4598 is available in small 20-pin SSOP, SO, and DIP packages.

Applications

ADC Systems Battery-Operated Equipment Test Equipment Avionics Audio-Signal Routing Networking

Features

- V+ and GND Can Be Switched to the Output Channels
- 75Ω (max) On-Resistance
- Single-Ended or Differential Operation
- 2pC (typ) Charge Injection
- Latched or Unlatched Operation
- ♦ TTL-Compatible Logic Inputs at ±5V Supply
- + Handles Rail-to-Rail Analog Signals

Ordering Information

TEMP BANCE	PIN-PACKAGE
TEMP. RANGE	PIN-PACKAGE
0°C to +70°C	20 SSOP
0°C to +70°C	20 Wide SO
0°C to +70°C	20 Plastic DIP
0°C to +70°C	Dice*
-40°C to +85°C	20 SSOP
-40°C to +85°C	20 Wide SO
-40°C to +85°C	20 Plastic DIP
	0°C to +70°C 0°C to +70°C 0°C to +70°C -40°C to +85°C -40°C to +85°C

Pin Configuration/Functional Diagram

*Contact factory for dice specifications.



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

Maxim Integrated Products 1

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ABSOLUTE MAXIMUM RATINGS

V+ to GND	0.3V to +13V
V- to GND	13V to +0.3V
V+ to V	0.3V to +13V
A_, EN, LATCH, NLATCH, NO_, CO	M_
(Note 1)	(V 0.3V) to (V+ + 0.3V)
Continuous Current (any terminal)	±20mA
Peak Current, NO_, or COM_	
(pulsed at 1ms, 10% duty cycle ma	ax)±40mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)
SSOP (derate 8mW/°C above +70°C)640mW
Wide SO (derate 10mW/°C above +70°C)800mW
Plastic DIP (derate 10.53mW/°C above +70°C)889mW
Derating Temperature Ranges
MAX4598C_P0°C to +70°C
MAX4598E_P40°C to +85°C
torage Temperature Range65°C to +160°C
ead Temperature (soldering, 10sec)+300°C

Note 1: Signals on NO_, COM_, EN, LATCH, NLATCH, or A_ exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +5V ±10%, V- = -5V ±10%, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	COND	MIN	TYP	MAX	UNIT	
SWITCH	ľ						
Analog Signal Range	V _{COM_} , V _{NO_}	(Note 3)		V-		V+	V
		$I_{COM} = 1mA,$	$T_A = +25^{\circ}C$		45	75	0
On-Resistance	Ron	V _{NO} = ±3.0V, V+ = 4.5V, V- = -4.5V	$T_A = T_{MIN}$ to T_{MAX}			100	Ω
On-Resistance Matching	4.0	$I_{COM} = 1mA,$	$T_A = +25^{\circ}C$		1	4	Ω
Between Channels (Note 4)	ΔR _{ON}	V _{NO} = ±3.0V, V+ = 4.5V, V- = -4.5V	$T_A = T_{MIN}$ to T_{MAX}			6	12
On-Resistance Flatness	Device	$I_{COM} = 1mA;$	$T_A = +25^{\circ}C$		7	10	0
(Note 5)	R _{FLAT}	V _{NO} = -3V, 0, 3V; V+ = 4.5V, V- = -4.5V	$T_A = T_{MIN}$ to T_{MAX}			13	Ω
NO Off-Leakage Current (Note 6)		$V_{NO_{-}} = \mp 4.5V,$ $V_{COM_{-}} = \pm 4.5V,$ $V_{+} = 5.5V, V_{-} = -5.5V$	$T_A = +25^{\circ}C$	-0.1	0.01	0.1	- nA
	INO(OFF)		$T_A = T_{MIN}$ to T_{MAX}	-2		2	
COM Off-Leakage Current		$V_{COM} = \pm 4.5V,$ $V_{NO} = \mp 4.5V,$ $V_{+} = 5.5V, V_{-} = -5.5V$	$T_A = +25^{\circ}C$	-0.2	0.01	0.2	nA
(Note 6)	ICOM(OFF)		$T_A = T_{MIN}$ to T_{MAX}	-10		10	ΠA
COM On-Leakage Current		$V_{COM} = \pm 4.5V,$ $V_{NO} = \pm 4.5V,$	$T_A = +25^{\circ}C$	-0.2	0.01	0.2	nA
(Note 6)	ICOM(ON)	$V_{NO} = \pm 4.5 V$, $V_{+} = 5.5 V$, $V_{-} = -5.5 V$	$T_A = T_{MIN}$ to T_{MAX}	-10		10	ΠA
LOGIC INPUTS						1	
Input High Voltage	VIH			2.4	1.7		V
Input Low Voltage	VIL				1.4	0.8	V
Input Current with Input Voltage High	ЦН	$V_{EN} = V_{A_{-}} = V_{LATCH} = V_{NLATCH} = V_{CAL} = V_{+}$		-0.1	0.01	0.1	μA
Input Current with Input Voltage Low	IIL	V _{EN} = V _A = V _{LATCH} =	-0.1	0.01	0.1	μΑ	

M/X/M

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

 $(V_{+} = +5V \pm 10\%, V_{-} = -5V \pm 10\%, V_{IH} = 2.4V, V_{IL} = 0.8V, T_{A} = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_{A} = +25^{\circ}$ C.) (Note 2)

PARAMETER					TYP	MAX	UNIT
SUPPLY							
Power-Supply Range				±2.7		±6	V
Positive Supply Current	+	V _{EN} = V _A = V _{LATCH} = V _{NLATCH} = 0 or V+,	$T_A = +25^{\circ}C$	-1	0.001	1	μA
		$V_{+} = 5.5V, V_{-} = -5.5V$	$T_A = T_{MIN}$ to T_{MAX}	-5		5	P' .
Negative Supply Current	-	V _{EN} = V _A = V _{LATCH} = V _{NLATCH} = 0 or V+,	$T_{A} = +25^{\circ}C$	-1	0.001	1	μA
			$T_A = T_{MIN}$ to T_{MAX}	-5		5	P
GND Supply Current	IGND	$V_{EN} = V_A = V_{LATCH}$ = $V_{NLATCH} = 0 \text{ or } V_+,$	T _A = +25°C	-1	0.001	1	μA
ond supply surrent	IGND	$V_{+} = 5.5V, V_{-} = -5.5V$	$T_A = T_{MIN}$ to T_{MAX}	-5		5	μ
DYNAMIC							
Transition Time	t TRANS	Figure 1	$T_A = +25^{\circ}C$		65	100	ns
	TRANS		$T_A = T_{MIN}$ to T_{MAX}			150	
Break-Before-Make Interval (Note 3)	topen	Figure 2	$T_A = +25^{\circ}C$	4	10		ns
Enable Turn-On Time	ton	Figure 3	$T_A = +25^{\circ}C$		55	90	ns
	UN		$T_A = T_{MIN}$ to T_{MAX}			120	
Enable Turn-Off Time	toff	Figure 3	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to T_{MAX}		40	70 100	ns
Charge Injection (Note 3)	V _{CTE}	$C_L = 1nF$, $V_{NO_} = 0$, Figure 4	$T_A = +25^{\circ}C$		2	5	рС
Off-Isolation (Note 7)	VISO	V _{EN} = 0, f = 1MHz, Figure 5	$T_A = +25^{\circ}C$		-90		dB
Crosstalk Between Channels (Note 8)	V _{CT}	$\label{eq:VEN} \begin{array}{l} V_{EN} = 2.4V, \ f = 1MHz, \\ V_{GEN} = 1Vp\text{-}p, \\ Figure \ 5 \end{array}$	$T_A = +25^{\circ}C$		-80		dB
Logic Input Capacitance	CIN	f = 1MHz	$T_A = +25^{\circ}C$		3		рF
NO Off-Capacitance	C _{OFF}	f = 1MHz, V _{EN} = V _{COM} = 0, Figure 6	$T_A = +25^{\circ}C$		3		pF
COM Off-Capacitance	C _{COM(OFF)}	$ f = 1MHz, \\ V_{EN} = V_{COM_{-}} = 0, \\ Figure 6 $	$T_A = +25^{\circ}C$		15		pF
COM On-Capacitance	C _{COM} (ON)	$ f = 1 MHz, V_{EN} = 2.4 V, \\ V_{COM} = 0 $	T _A = +25°C		26		рF
LATCH TIMING (Note 3)		-	1	1			
Setup Time	ts	Figure 7	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to T_{MAX}		30	70 80	ns
Hold Time	t.,	Figure 7	$T_A = +25^{\circ}C$	-10	0	00	nc
	tH	i iguic /	$T_A = T_{MIN}$ to T_{MAX}	-10			ns

ELECTRICAL CHARACTERISTICS—Single +5V Supply

(V+ = +5V \pm 10%, V- = 0, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	COND	MIN	TYP	MAX	UNIT		
SWITCH	1	1		1				
Analog Signal Range	V _{NO_} , V _{COM_}	(Note 3)		0		V+	V	
On-Resistance	Pou	$I_{COM} = 1mA$,	$T_A = +25^{\circ}C$		80	150	Ω	
	R _{ON}	$V_{NO_{-}} = 3.0V,$ V+ = 4.5V	$T_A = T_{MIN}$ to T_{MAX}			200	52	
On-Resistance Matching		$I_{COM} = 1mA,$	$T_A = +25^{\circ}C$		2	8	Ω	
Between Channels (Notes 3, 4)	ΔR _{ON}	$V_{NO_{-}} = 3.0V,$ V+ = 4.5V	$T_A = T_{MIN}$ to T_{MAX}			12	52	
On-Resistance Flatness	R _{FLAT}	I _{COM} = 1mA; V _{NO} = 3V, 2V, 1V; V+ = 4.5V	$T_A = +25^{\circ}C$		8		Ω	
NO Off-Leakage Current		$V_{NO} = 4.5V, 1V;$	$T_A = +25^{\circ}C$	-0.1		0.1		
(Notes 6, 9)	I _{NO(OFF)}	V _{COM} = 1V, 4.5V; V+ = 5.5V	$T_A = T_{MIN}$ to T_{MAX}	-2		2	nA	
COM Off-Leakage Current (Notes 6, 9)		$V_{COM} = 4.5V, 1V;$	$T_A = +25^{\circ}C$	-0.2		0.2	nA	
	ICOM(OFF)	$V_{NO_{-}} = 1V, 4.5V;$ V+ = 5.5V	$T_A = T_{MIN}$ to T_{MAX}	-10		10		
COM On-Leakage Current		$V_{COM} = 4.5V,$	$T_A = +25^{\circ}C$	-0.2		0.2		
(Notes 6, 9)	ICOM(ON)	$V_{NO_{-}} = 4.5V,$ V+ = 5.5V	$T_A = T_{MIN}$ to T_{MAX}	-10		10	- nA	
LOGIC INPUTS (Note 3)	1			I		I		
Input High Voltage	VIH			2.4	1.6		V	
Input Low Voltage	VIL				1.3	0.8	V	
Input Current with Input Voltage High		V _{EN} = V _{LATCH} = V _A =	V _{NLATCH} = V+	-0.1	0.01	0.1	μA	
Input Current with Input Voltage Low		V _{EN} = V _{LATCH} = V _A =	VNLATCH = 0	-0.1	0.01	0.1	μΑ	
SUPPLY	1			1		I		
Power-Supply Range				2.7		12.0	V	
Positive Supply Current (Note 3)	+	$V_{EN} = V_A = V_{LATCH}$ $T_A = +25^{\circ}C$		-1		1	μA	
		= V_{NLATCH} = 0 or V+, V+ = 5.5V T _A = T _{MIN} to T _{MAX}		-5		5	μΑ	
DYNAMIC (Note 3)			-					
Transition Time	t TRANS	V _{NO} _ = 3V, Figure 1	$T_{A} = +25^{\circ}C$ $T_{A} = T_{MIN} \text{ to } T_{MAX}$		115	160 210	ns	
Break-Before-Make Interval	topen	Figure 2 $T_A = +25^{\circ}C$		4	10		ns	
			$T_{A} = +25^{\circ}C$		85	140		
Enable Turn-On Time	ton	Figure 3	$T_A = T_{MIN}$ to T_{MAX}			170	ns	
Enable Turn-Off Time	toff	Figure 3	$T_A = +25^{\circ}C$		60	100	ns	
	, UFF		Figure 3 $T_A = T_{MIN}$ to T_{MAX}			120	115	

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

(V+ = +5V \pm 10%, V- = 0, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNIT
Charge Injection	V _{CTE}	$C_L = 1nF$, $V_{NO_} = 0$, Figure 4	$T_A = +25^{\circ}C$		1	5	рС
LATCH TIMING (Note 3)							
Setup Time	to	Figure 7	$T_A = +25^{\circ}C$		30	70	ns
Setup Time	ts		$T_A = T_{MIN}$ to T_{MAX}			80	115
Hold Time	tн	Figure 7	$T_A = +25^{\circ}C$	-10	0		ns
	Ч		$T_A = T_{MIN}$ to T_{MAX}	-10			115

ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V + = +2.7V \text{ to } +3.6V, V - = 0, V_{IH} = 2.4V, V_{IL} = 0.6V, T_A = T_{MIN} \text{ to } T_{MAX}$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C.$)

PARAMETER	SYMBOL	CON	MIN	TYP	MAX	UNIT	
SWITCH				4			
Analog Signal Range		(Note 3)		0		V+	V
On-Resistance	Ron	I _{COM} _ = 0.2mA, V _{NO} _ = 1.5V,	$T_A = +25^{\circ}C$		220	500	Ω
	KON	$V_{\rm HO} = 1.3 V_{\rm c}$ V + = 2.7V	$T_A = T_{MIN}$ to T_{MAX}			600	52
LOGIC INPUTS (Note 3)							
Input High Voltage	ЦН			2.4	1.1		V
Input Low Voltage	IIL				1.0	0.6	V
DYNAMIC (Note 3)	i						
Transition Time	t trans	V _{NO1} = 1.5V, V _{NO8} = 0, Figure 1	$T_{A} = +25^{\circ}C$		200	310	ns
Enable Turn-On Time	t _{ON}	V _{NO1} = 1.5V, Figure 3	$1 1 4 = \pm 75^{-1}$		160	250	ns
Enable Turn-Off Time	toff	V _{NO1} = 1.5V, Figure 3	$T_{A} = +25^{\circ}C$		120	180	ns
LATCH TIMING (Note 3)	I		•				
Setup Time	ts	Figure 7	$T_A = +25^{\circ}C$		45	80	ns
Hold Time	t _H	Figure 7	$T_A = +25^{\circ}C$	-10	0		ns

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: $\Delta R_{ON} = R_{ON}(MAX) - R_{ON}(MIN)$.

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.

Note 6: Leakage parameters are 100% tested at maximum-rated hot temperature and guaranteed by correlation at +25°C.

Note 7: Off-Isolation = $20\log_{10}(V_{COM} / V_{NO})$, V_{COM} = output, V_{NO} = input to off switch.

Note 8: Between any two switches.

Note 9: Leakage testing at single supply is guaranteed by testing with dual supplies.

MAX4598

Typical Operating Characteristics

ON-RESISTANCE vs. VCOM ON-RESISTANCE vs. VCOM AND ON-RESISTANCE vs. VCOM AND **TEMPERATURE (DUAL SUPPLIES) TEMPERATURE (SINGLE SUPPLY)** (SINGLE SUPPLY) 60 90 190 +85 -70°C 80 170 50 70 150 $V_{+} = +2.7V_{-}$ 40 60 +85°C ٠TA 130 R_{ON} (Ω) G G 50 110 30 Ron RoN +25°C 40 Tμ +25°C 1 40°C T_A = 90 20 30 -40°C TΑ 70 V+ +51 20 10 $V_{+} = +5V$ V + = +5V50 10 $V_{-} = 0$ V- = -5V 0 0 30 0.5 1.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0 0.5 1.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0 -5 -4 -3 -2 -1 0 1 2 3 4 5 0 0 V_{COM} (V) V_{COM} (V) V_{COM} (V) ON-RESISTANCE vs. VCOM LEAKAGE CURRENT (DUAL SUPPLIES) vs. TEMPERATURE SUPPLY CURRENT vs. TEMPERATURE 100n 110 1000n V + = +5V100n 100 -5V 10n 10n 90 E 1n LEAKAGE CURRENT 80 V+ = +2.7V COM (ON) $R_{ON}\left(\Omega\right)$ 100p V. -27V 70 V--3V 10p -3V 60 CON (OFF) 1р 50 V+ +5V 100f NO (OFF V - = -5V100f 40 10f 30 10f 1f -5 -4 -3 -2 -1 0 2 3 4 5 -40 -20 0 20 40 60 80 100 120 -40 -20 0 20 40 60 80 100 120 140 1 V_{COM} (V) TEMPERATURE (°C) TEMPERATURE (°C) **TURN-ON/TURN-OFF TIMES** TURN-ON/TURN-OFF TIMES vs. SUPPLY VOLTAGE (DUAL SUPPLIES) vs. TEMPERATURE 80 140 V + = +5VV - = -5V120 70 100 60 toFF (ns) ton, torr (ns) 80 ton ton 50 ton, 60 toff 40 40 toff 30 20 0 20 2 3 5 4 -40 0 25 70 85 V+, V- (V) TEMPERATURE (°C)

M/IXI/M

MAX4598

 $(T_A = +25^{\circ}C, unless otherwise noted.)$

Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, unless otherwise noted.)$



Pin Description

PIN	NAME	FUNCTION
1	COMB	Multiplexer Output B
2	A1	Address Bit 1
3	A0	Address Bit 0
4	NO4	Channel Input 4
5	NO2	Channel Input 2
6	NO3	Channel Input 3
7	NO1	Channel Input 1
8	V-	Negative Supply Voltage
9	V+	Positive Supply Voltage
10	COMA	Multiplexer Output A
11	NLATCH	Data-Strobe Mode Select
12	LATCH	Latch Input
13	EN	Multiplexer Enable
14	NO5	Channel Input 5
15	NO7	Channel Input 7
16	NO6	Channel Input 6
17	NO8	Channel Input 8
18	A3	Address Bit 3
19	A2	Address Bit 2
20	GND	Ground



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MAX4598

Detailed Description

The MAX4598 can be configured as a single 8-channel or dual 4-channel multiplexer. In the single 8-to-1 multiplexer configuration, COMA connects to one of the eight inputs (NO1 to NO8), GND, or V+ by the address inputs A0 to A2 (see *Truth Table*). In the dual 4-to-1 multiplexer configuration, COMA connects to one of the four inputs (NO1, NO3, NO5, NO7), GND, or V+, and COMB connects to one of the four inputs (NO2, NO4, NO6, NO8) or GND by the address inputs A0 to A2 (see *Truth Table*).

The MAX4598 functions as a standard multiplexer when NLATCH is high. When NLATCH is low, the condition set by A0 to A3 is activated at the rising edge of LATCH. Otherwise, the outputs remain at the previously set condition.

Applications Information

The MAX4598 construction is typical of most CMOS analog switches. It has three supply pins: V+, V-, and GND. The positive and negative power supplies are used to drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD-protection diodes are internally connected between each analog signal pin and V+ and V-. If the voltage on any pin exceeds V+ or V- by 0.3V, one of the ESD diodes starts to conduct. During normal operation these reverse-biased ESD diodes leak, forming the only current drawn from V-.



Truth Table

A3	A2	A1	A0	EN	LATCH	NLATCH	СОМА	COMB
х	х	х	х	0	Х	Х	High-Z	High-Z
х	х	x	x	1		0	State is latched on the rising edge of LATCH	State is latched on the rising edge of LATCH
0	0	0	0	1	Х	1	NO1	GND
0	0	0	1	1	Х	1	NO2	GND
0	0	1	0	1	Х	1	NO3	GND
0	0	1	1	1	Х	1	NO4	GND
0	1	0	0	1	Х	1	NO5	GND
0	1	0	1	1	Х	1	NO6	GND
0	1	1	0	1	Х	1	NO7	GND
0	1	1	1	1	Х	1	NO8	GND
1	0	0	0	1	Х	1	NO1	NO2
1	0	0	1	1	Х	1	NO3	NO4
1	0	1	0	1	Х	1	NO5	NO6
1	0	1	1	1	Х	1	NO7	NO8
1	1	0	0	1	Х	1	GND	GND
1	1	0	1	1	Х	1	V+	GND
1	1	1	0	1	Х	1	NO8	NO8
1	1	1	1	1	Х	1	High-Z	High-Z

x = Don't care

MAX4598

Virtually all the analog leakage current is through the ESD diodes. Although the ESD diodes on a given signal pin are identical, and therefore fairly well balanced, they are reverse-biased differently. Each is biased by either V+ or V- and the analog signal. This means their leakage varies as the signal varies. The difference in the two diodes' leakage from the signal path to the V+ and V- pins constitutes the analog signal-path leakage current. All analog leakage current flows to the supply terminals, not to the other switch terminal. This explains how both sides of a given switch can show leakage currents of either the same or opposite polarity.

There is no connection between the analog signal paths and GND. The analog signal paths consist of an N-channel and a P-channel MOSFET, with their sources and drains paralleled and their gates driven out of phase with V+ and V- by the logic-level translators.

V+ and GND power the internal logic and logic-level translators, and set the input logic thresholds. The logic-level translators convert the logic levels to switched V+ and V- signals to drive the analog switch gates. This drive signal is the only connection between

the logic supplies and the analog supplies. All pins have ESD protection to V+ and to V-.

Increasing V- has no effect on the logic-level thresholds, but it does increase the drive to the P-channel switches, reducing their on-resistance. V- also sets the negative limit of the analog signal voltage.

The logic-level thresholds are CMOS- and TTL-compatible when V+ is +5V. As V+ is raised, the threshold increases slightly; when V+ reaches +12V, the level threshold is about 3.2V, which is above the TTL output high-level minimum of 2.4V but still compatible with CMOS outputs.

Bipolar-Supply Operation

The MAX4598 operates with bipolar supplies between $\pm 2.7V$ and $\pm 6V$. The V+ and V- supplies need not be symmetrical, but their sum cannot exceed the absolute maximum rating of 13V. Do not connect the MAX4598 V+ pin to +3V and connect the logic-level input pins to TTL logic-level signals. TTL logic-level outputs can exceed the absolute maximum ratings, causing damage to the part and/or external circuits.

Caution: The absolute maximum V+ to V- differential voltage is 13V. Typical "±6 Volt" or "12 Volt" supplies with ±10% tolerances can be as high as 13.2V from V+ to V-. This voltage can damage the MAX4598. Even ±5% tolerance supplies may have overshoot or noise spikes that exceed 13V.

Single-Supply Operation

The MAX4598 operates from a single supply between +2.7V and +12V when V- is connected to GND. All of the bipolar precautions must be observed. However, these parts are optimized for ±5V operation, and most AC and DC characteristics are degraded significantly when departing from ±5V. As the overall supply voltage (V+ to V-) is lowered, switching speed, on-resistance,

off-isolation, and distortion are degraded (see Typical Operating Characteristics).

Single-supply operation also limits signal levels and interferes with grounded signals. When V- = 0, AC signals are limited to -0.3V. Voltages below -0.3V can be clipped by the internal ESD-protection diodes, and the parts can be damaged if excessive current flows.

Power Off

When power to the MAX4598 is off (i.e., V + = V - = 0), the Absolute Maximum Ratings still apply: neither logiclevel inputs on NO_ nor signals on COM_ can exceed ±0.3V. Voltages beyond ±0.3V cause the internal ESDprotection diodes to conduct, and the parts can be damaged if excessive current flows.

Test Circuits/Timing Diagrams



Figure 1. Transition Time



Figure 2. Break-Before-Make Interval

///XI///



t_R < 20ns +5V t_F < 20ns V+ V_{EN} 50% 50% NLATCH V+ 0V VEN ΕN NO1 +3V LATCH N02-N08 Δ3 MAXIM VOUT MAX4598 A0 90% 90% A1 COMA VOUT $\leq 50\Omega$ A2 GND ́л V-35pF -5V

Figure 3. Enable Switching Time



Figure 4. Charge Injection



Figure 5. Off-Isolation/Crosstalk

Test Circuits/Timing Diagrams (continued)

- t_{OFF}

0V

t_{ON}

/N/XI/N



Test Circuits/Timing Diagrams

Figure 6. NO_/COM_ Capacitance



Figure 7. Setup Time, Hold Time



TRANSISTOR COUNT: 287 SUBSTRATE CONNECTED TO V+

NOTES

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
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Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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